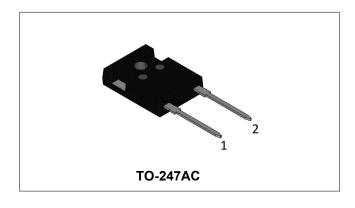






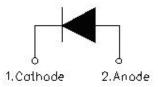
SDUR6060W ULTRAFAST RECTIFIER



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram



Features

- Ultra-Fast switching
- · High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: 100% Pure Tin
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings(limiting values, T_C =25°C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	600	V
Average Rectified Forward Current	I _{F (AV)}	Tc=109°C, In DC	60	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	400	Α

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@30A, Pulse, T _J = 25°C @ 60A, Pulse, T _J = 25°C	1.42 1.64	- 2.0	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$	1	100	uA
	I _{R2}	@V _R = rated V _R T _J =125°C	1	14	mA
Reverse Recovery Time	t _{rr}	I _F =500mA,I _R =1A,and I _m =250mA	43	50	ns
Reverse Recovery Time	t _{rr}		38	-	ns
Reverse Recovery Charge	Qrr] I _F = 1A, diF/dt = 100A/µs] V _R = 30V, T _J = 25°C	45	-	nC
Reverse Recovery Current	I _{RRM}	,	2.4	-	Α
Reverse Recovery Time	t _{rr}	I _F = 60A, diF/dt = 200A/μs	70	-	ns
Reverse Recovery Charge	Qrr	$V_R = 400V, T_J = 25^{\circ}C$	280	-	nC
Reverse Recovery Current	I _{RRM}		8	-	Α
Reverse Recovery Time	t _{rr}	I _F = 60A, diF/dt = 200A/µs	120	-	ns
Reverse Recovery Charge	Qrr	$V_R = 400V, T_J = 125^{\circ}C$	576	-	nC
Reverse Recovery Current	I _{RRM}		10	-	Α

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

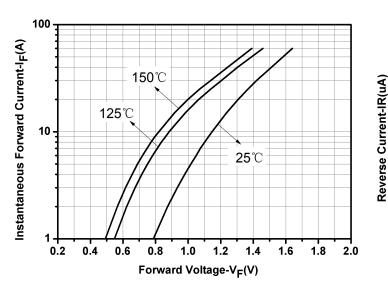
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _θ JC	DC operation	0.34	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			







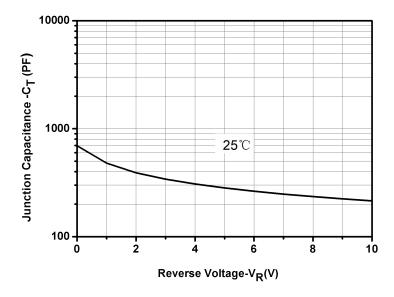
Ratings and Characteristics Curves



100000 10000 150℃ 🗏 1000 **125**℃ 100 10 -25℃ 1 0.1 240 360 480 120 600 Reverse Voltage- $V_R(V)$

Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics



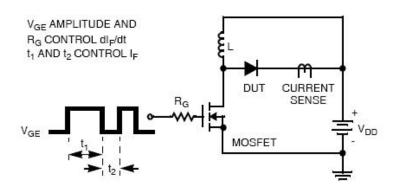


Fig.3-Capacitance vs. Reverse Voltage

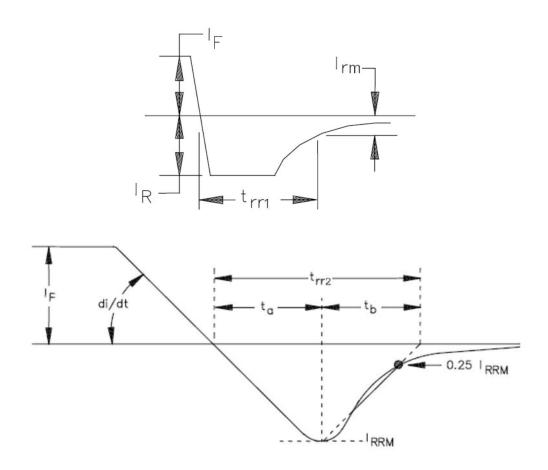
Fig.4-Diode Test Circuit

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Note: 1. t_{rr1} MIL-STD-750 Test Method 4031, condition "B". 2. t_{rr2} MIL-STD-750 Test Method 4031, condition "D" .

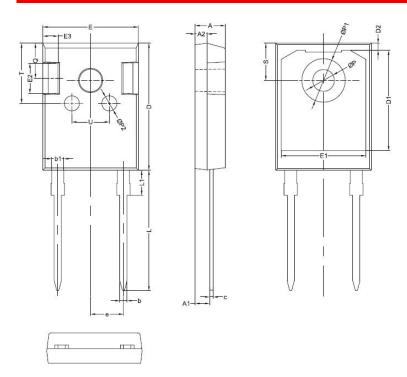
Fig.5-Reverse Recovery Waveform





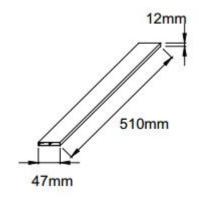


Mechanical Dimensions TO-247AC

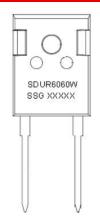


CVMPOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A1	2.20	2.41	2.61	
A2	1.90	2.00	2.10	
b	1.10	1.20	1.35	
b1	1.80	2.00	2.20	
С	0.50	0.60	0.75	
D	20.30	21.00	21.20	
D1		16.58		
D2		1.17		
Е	15.60	15.80	16.00	
E1		14.02		
E2		5.00		
E3		2.50		
е		5.44		
L	19.42	19.92	20.42	
L1		4.13		
Р	3.50	3.60	3.70	
P1	7.1	7.19	7.40	
P2		2.50		
Q		5.80		
Q S T	6.05	6.15	6.25	
T		10.00		
U		6.20		

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

SDUR = Device Type 60 = Forward Current (60A) 60 = Reverse Voltage (600V) W = Configuration = SSG = SSG

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping	
SDUR6060W	TO-247AC(Pb-Free)	25pcs / tube	

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